

# 10-V TO 24-V INPUT, 5-V OUTPUT, 2.1-A STEP-DOWN VOLTAGE CONVERTER

Check for Samples: TPS5480, TPS5481

#### **FEATURES**

- 5-V Synchronous/Asynchronous Hysteretic Switching Regulator
- Low Output Ripple and Allows Ceramic Output Capacitor
- Fault Conditions Monitored:
  - Over- and Under-Voltage
  - Over-Temperature
  - Over-Current
- Wide V<sub>IN</sub> Input Range: 10 V to 24 V
- · Pre-Biased and Adjustable Soft Start
- Highly Efficient Integrated FETs: < 120 mΩ (High Side only)
- Capacitor Based Boost Circuit

- Over Current Protection
- High Accuracy Internal Bandgap, Oscillator, Reference Current and Margin Voltage

#### **APPLICATIONS**

- Wide Range of Applications for Low-Voltage, High-Current Systems
  - Up to 2.1-A High-Efficiency Step-Down Regulator
  - Battery Charger
  - High-Efficiency Preregulator (5 V)

#### **DESCRIPTION**

The TPS5480 and TPS5481 are positive, hysteretic, 5-V, 2.1-A, 200-kHz (TPS5480) or 400-kHz (TPS5481) switching regulators with wide input voltage range of 10 V to 24 V. They require either an external, low forward-voltage Schottky diode or a power MOSFET. Internal digital control logic is used to sequence the output of a fast comparator before applying it to the input of the MOSFET gate driver. A pin selectable soft start circuit is present to reduce current draw and overshoot during power up. The EN pin enables the regulator output when forced high (tied to V3P3 pin); an internal pull-down resistor disables the regulator when the EN pin is not connected. The internal 3.3-V linear regulator provides power for the enable pin.

#### ORDERING INFORMATION(1)

PACKAGE <sup>(2)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
(OFN) DCT	TPS5480	TBD		
(QFN) - RGT	TPS5481	TBD		

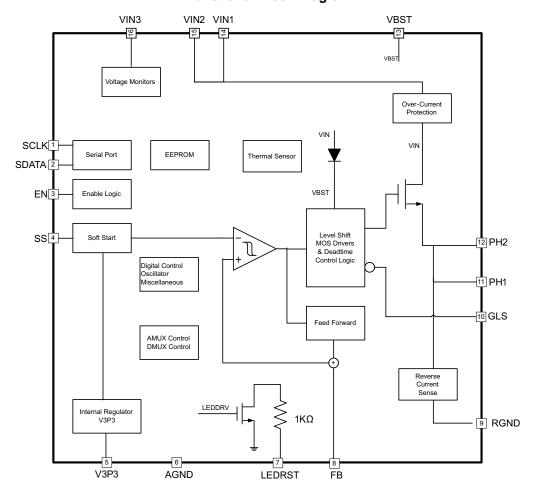
- (1) For the most current packaging and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



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## **DEVICE INFORMATION**

## **Functional Block Diagram**



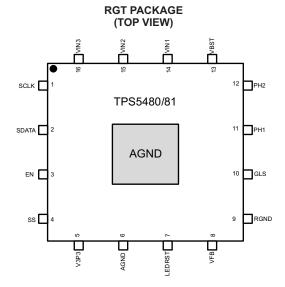


## **Table 1. TERMINAL FUNCTIONS**

NAME	PIN	DESCRIPTION		
SCLK	1	Serial port clock		
SDATA	2	Serial port data		
EN	3	Regulator enable		
SS	4	Programmable soft-start		
V3P3	5	Linear regulator output used for EN pin		
AGND	6	Analog ground		
LEDRST	7	Current sink for LED		
VFB	8	Converter feedback input. Connect with output of converter.		
RGND	9	Ground return for low-side driver and reverse-current sense		
GLS	10	Gate voltage for external low-side FET		
PH1, PH2	11, 12	Switch node connection between high-side NFET and low-side NFET		
VBST	13	Supply input for high-side NFET gate driver (boost terminal)		
VIN1, VIN2	14, 15	Power input connected to high-side NFET drain		
VIN3	16	Input to over- and under-voltage monitor		

## **Table 2. RECOMMENDED EXTERNAL COMPONENTS**

PIN	то	FUNC	VALUE	UNIT		
VIN1, VIN2, VIN3	AGND	Noise decoupling capacitor	20	μF		
PH1, PH2	VBST	Boost Capacitor	Boost Capacitor			
DIM DIIO	VOLIT	Output filter to Malta as a comb	Inductor (ESR < 60mΩ)	> 22	μH	
PH1, PH2	VOUT	Output filter to Voltage supply  Capacitor (ESR < 10mΩ)		20	1F	
V3P3	AGND	Internal regulator capacitor	Internal regulator capacitor			
00	AGND	Optional for faster soft-start	66	kΩ		
SS	V3P3	Optional for slower soft-start	66			
PH1, PH2	RGND	Schottky diode or	< 0.55	V		
PH1, PH2	GLS, RGND	Extenal low-side NFET with GLS p	Extenal low-side NFET with GLS pin to gate			





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# ABSOLUTE MAXIMUM RATINGS(1)(2)

		CONDITIONS	VALUE	UNIT
V <sub>IN1,2,3</sub>	Input voltage <sup>(1)</sup>	T <sub>A</sub> = 25°C	-1 to 30	V
V <sub>PH1,2</sub>	Phase voltage	T <sub>A</sub> = 25°C	-1 to 30	V
V <sub>BST</sub>	Boost voltage (wrt V <sub>PH1,2</sub> )	T <sub>A</sub> = 25°C	-1 to V <sub>PH</sub> + 7	V
V <sub>FB</sub>	Regulator feedback voltage	T <sub>A</sub> = 25°C	-0.3 to 7	V
V <sub>LEDRST</sub>	LED current sink	T <sub>A</sub> = 25°C	-0.3 to 7	V
	Voltage on other pins		-0.3 to 3.6	V
T <sub>FA</sub>	Operating free-air temperature		-10 to 60	°C
T <sub>J</sub>	Operating junction temperature		160	°C
$\theta_{JA}$	Junction-to-ambient thermal resistance		47.4	°C/W
T <sub>stg</sub>	Storage temperature		-55 to 150	°C
P <sub>DISS</sub>	Total power dissipation with device appropriately mounted <sup>(2)</sup>	T <sub>A</sub> = 25°C	2.7	W
ESD <sub>HBM</sub>	Human body model		2000	V
ESD <sub>CDM</sub>	Charged device model		500	V

<sup>(1)</sup> Stresses beyond those under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. All voltages are with respect

#### RECOMMENDED OPERATING CONDITIONS

 $T_A = 25$ °C (unless otherwise noted)

		MIN	NOM MAX	UNIT
V <sub>IN1,2,3</sub>	Input voltage	10	24	V
V <sub>PH1,2</sub>	Phase voltage	10	24	V
V <sub>BST</sub>	Boost voltage	PH	PH+7	V
$V_{FB}$	Regulator feedback voltage		5	V
V <sub>LEDRST</sub>	LED current sink		5	V
	Voltage on other pins		3.3	V

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This number is listed for reference only based on typical junction-to-ambient thermal resistance ( $\theta_{JA}$ ). The maximum power should be determined by final thermal characteristics for the application in order to maintain a maximum die temperature that is less than 150°C.



## **ELECTRICAL CHARACTERISTICS**

 $T_A = 25^{\circ}C$  (unless otherwise noted)

$T_A = 25^{\circ}C$ (	unless otherwise noted)					
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
BUCK REG	ULATOR OUTPUT					
$V_{FB}$	V <sub>OUT</sub> output voltage	T <sub>A</sub> = 25°C, 10 V < V <sub>IN</sub> < 24 V, 0 < I <sub>LOAD</sub> < 2.1 A	4.85	5.15	5.45	V
$V_{ripple}$	V <sub>OUT</sub> ripple voltage	$T_A = 25^{\circ}\text{C},$ 10 V < V <sub>IN</sub> < 24 V, 0 < I <sub>LOAD</sub> < 2.1 A, Continuous mode at 200 kHz			100	mV
V <sub>HYS</sub>	Comparator hysteresis		20	25	30	mV
V <sub>OS</sub>	V <sub>OUT</sub> output overshoot		-20%	$V_{FB}$	20%	V
SUPPLY QU	JIESCENT CURRENT					
$I_Q$	Quiescent current (V <sub>IN</sub> )	EN = 1, no load			10	mA
SOFT STAR	RT					
		SS = no connect	1.5	2.75	4	
$V_{OUT}$	Ramp time	SS = Pullup to V3P3 (66 kΩ)	2.25	4	5.75	ms
		SS = Pulldown to AGND (66 k $\Omega$ )	0.75	1.5	2.25	
MOSFET						
R <sub>dsONHS</sub>	High side switch resistance	T <sub>A</sub> = 125°C			0.12	Ω
	RENT SHUTDOWN PROTECTION				"	
I <sub>ocs</sub>	Over-current limit (average load current)	T <sub>A</sub> = 25°C, L = 22 μH at 200 kHz, 10 V < V <sub>IN</sub> < 24 V	2.3		2.8	Α
THERMAL S	SHUTDOWN PROTECTION					
T <sub>EOTW</sub>	Early over temperature warn		170	180	190	°C
T <sub>OTS</sub>	Over temperature shutdown		180	190	200	°C
VOLTAGE I	MONITORS				'	
V <sub>OVR</sub>	Over-voltage rising trip point		28	28.6	29.2	
V <sub>OVF</sub>	Over-voltage falling trip point		27.3	27.9	28.5	.,
$V_{UVR}$	Under-voltage rising trip point		8.2	8.5	8.8	V
V <sub>UVF</sub>	Under-voltage falling trip point		7.7	8	8.3	
FEED FORV	WARD FREQUENCY				'	
,	0 11 1	TPS5480	120	200	280	kHz
t <sub>SW</sub>	Switching frequency	TPS5481	250	400	550	kHz
LED DRIVE	R					
I <sub>LED</sub>	LED sink current				7	mA
V <sub>LED</sub>	LED voltage				7	V
	R EFFICIENCY				'	
		Inductor = 22 $\mu$ H, 60 m $\Omega$ ESR				
		Load capacitor = 20 μF, 10 mΩ ESR				
		$V_{IN}$ capacitor = 20 $\mu$ F, 10 m $\Omega$ ESR				
Efficiency		VBST capacitor = 100 nF, 10 mΩ ESR				
(Reference only)	$f_{SW} = 200 \text{ kHz}, V_{IN} = 10 \text{ V} - 24 \text{ V}^{(1)}$	V3P3 capacitor = 100 nF, 10 mΩ ESR	75			%
Oy /		Load current = 2.1 A				
		V <sub>F</sub> , Schottky diode < 0.55 V				
		T <sub>A</sub> = 25°C				
LOGIC ENA	BLE PIN					
		T <sub>A</sub> = 25°C	2			
$V_{ENH}$	En nign-ievei input voltage	1 A = 23 C	_			
V <sub>ENH</sub>	EN high-level input voltage EN low-level input voltage	$T_A = 25^{\circ}C$			0.8	V

<sup>(1)</sup> Example only, measured with reference to device input and output pins.



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# **ELECTRICAL CHARACTERISTICS (continued)**

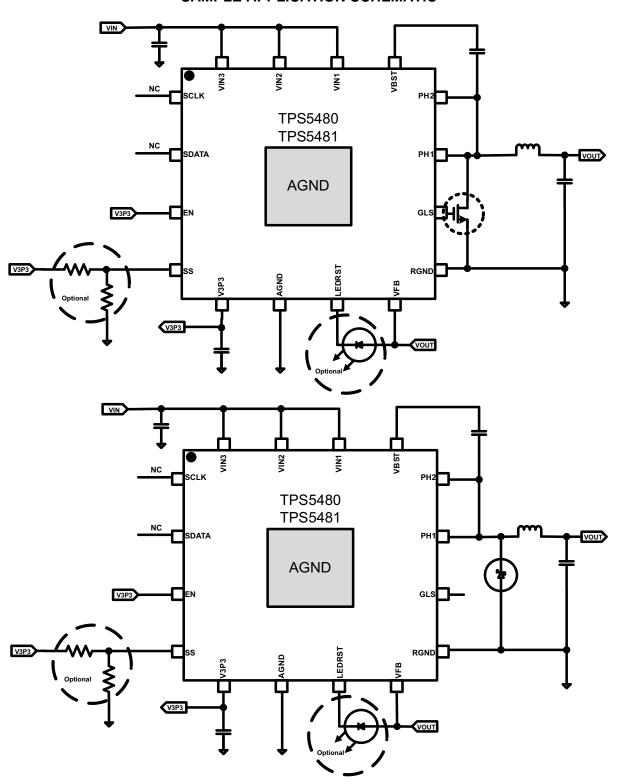
 $T_A = 25$ °C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT	
REGULATO	OR FOLDBACK CURRENT					
I <sub>Foldback</sub>	Foldback current (2)	10 V < V <sub>IN</sub> < 24 V	0	6	mA	
REGULATO	OR LOAD CURRENT					
I <sub>Load</sub>	Load current	$T_A = 25$ °C, L = 22 µH at 200 kHz	0	2.1	Α	
I <sub>Load</sub>	Load current	$T_A = 25$ °C, L = 22 $\mu$ H at 400 kHz		2.1	Α	

(2) Ensured by application board functional test.



## **SAMPLE APPLICATION SCHEMATIC**







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#### **PACKAGING INFORMATION**

Orderable Device	Status (1) P	ackage Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
TPS5480RGTR	PREVIEW	QFN	RGT	16		TBD	Call TI	Call TI	
TPS5480RGTT	PREVIEW	QFN	RGT	16		TBD	Call TI	Call TI	
TPS5481RGTR	PREVIEW	QFN	RGT	16		TBD	Call TI	Call TI	
TPS5481RGTT	PREVIEW	QFN	RGT	16		TBD	Call TI	Call TI	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

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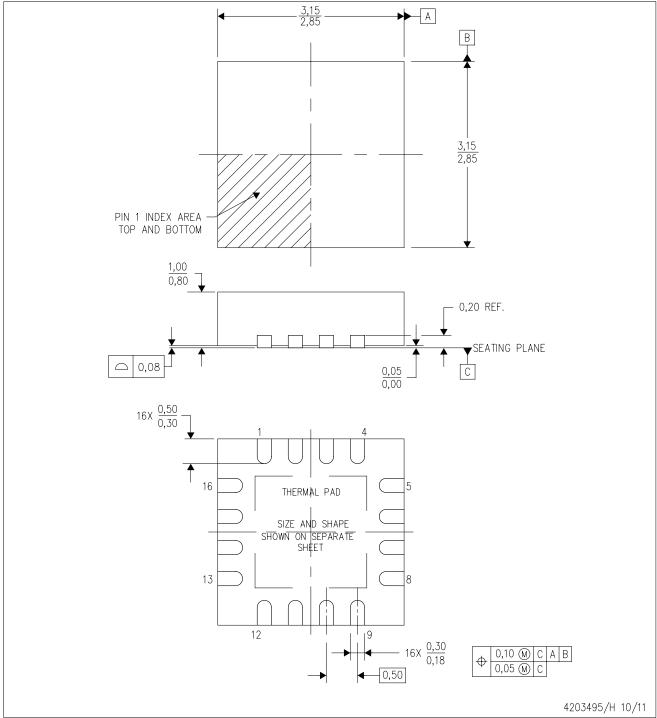
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# RGT (S-PVQFN-N16)

## PLASTIC QUAD FLATPACK NO-LEAD



NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.

- This drawing is subject to change without notice.
- Quad Flatpack, No-leads (QFN) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. Falls within JEDEC MO-220.



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